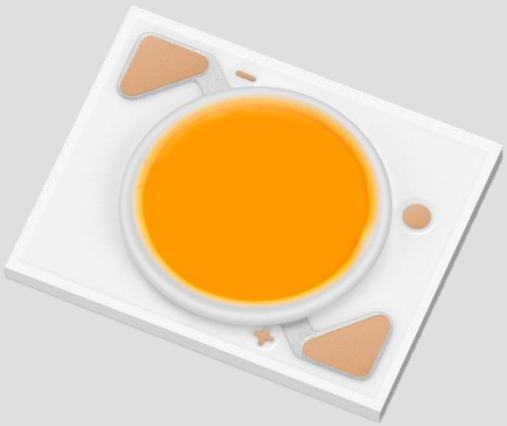
High Voltage LED Series
Chip on Board
- Small LES COB line-up -
LC020C



Small LES COBs are well-suited for compact spot light system

Features & Benefits

- Suitable for luminaires with narrow beam angle such as shop lighting
- Maximize Center Beam Candle Power(CBCP)
- Reduce lighting system cost with smaller optical component
- High reliability without wire-bonding

Applications

- Spotlight / Downlight
- LED Retrofit Bulbs

1. Characteristics

a) Absolute Maximum Rating

Item	Symbol	Rating	Unit
Ambient / Operating Temperature	T_a	-40 ~ +105	ºC
Storage Temperature	T_{stg}	-40 ~ +120	ºC
Case Temperature	Tc	105	ºC
LED Junction Temperature	T_J	140	ºC
Forward Current	I_F	810	mA
Minimum Current	I_{F_min}	20	mA
ESD (HBM)	-	±2	kV

Notes:

1) Refer to 4. Outline Drawing & Dimension for Tc point.
2) Refer to the Derating curve for proper driving current that maintained below Maximum junction temperature.

b) Electro-optical Characteristics (I_F = 540 mA, T_J = 85 ºC)

Item	Unit	Rank	Min.	Typ.	Max.
Forward Voltage (V_F) *1, *2	V	-	32.5	34.5	38.5
Color Rendering Index (R_a) *1, *2		5	80	-	-
		7	90	-	-
Thermal Resistance (Junction to Tc point)	ºC/W		-	1.6	1.9
Beam Angle	º		-	115	-

Notes:

1) The COB is tested in pulsed operating condition at rated test current (10 ms pulse width) and rated temperature (T_J = T_C = 85 °C).
2) Samsung maintains measurement tolerance of: Forward Voltage = ±5 %, CRI = ±1

2. Product Code Information

1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16	17	18
S	P	H	W	H	2	H	D	N	C	0	5	Y	H	V	3	C	1

Digit	PKG Information	Code	Specification		
1 2 3	Samsung Package High Power	SPH			
4 5	Color	WH	White		
6	Product Version	2	Version		
7 8	Form Factor	HD	COB		
9	Lens Type	N	No lens		
10	Internal Code	C	LC020C		
11	Chip Type	0	Minor version		
12	CRI & Sorting Temperature	5	Min. 80		
		7	Min. 90		
13 14	Forward Voltage (V)	YH	32.5~38.5		
15	CCT (K)	W	2700 K		
		V	3000 K		
		U	3500 K		
		T	4000 K		
		R	5000 K		
		Q	5700 K		
16	MacAdam / ANSI	2	MacAdam 2-step		
		3	MacAdam 3-step		
		T	ANSI bin		
17 18	Luminous Flux	C1	Ra min.80	2700K	C3, B3, A3
				3000K	D3, C3, B3
				3500K	E3, D3, C3
				4000K	E3, D3, C3
				5000K	F3, E3, D3
				5700K	F3, E3, D3
			Ra min.90	2700K	K2, H2, G2
				3000K	L2, K2, H2
				3500K	A3, L2, K2
				4000K	B3, A3, L2

a) 20W Luminous Flux Characteristics (I_F = 540 mA)

CRI (R_a)	Lumen Flux		Sorting[1] @ T_J = 85 °C (lm)		CCT					
Min.	Rank		Min.	Max.	2700K	3000K	3500K	4000K	5000K	5700K
80	G	3	2900	3110						
	F	3	2710	2900						
	E	3	2540	2710						
	D	3	2370	2540						
	C	3	2220	2370						
	B	3	2070	2220						
	A	3	1930	2070						
	L	2	1810	1930						
	K	2	1690	1810						
	H	2	1580	1690						
	G	2	1480	1580						
	F	2	1380	1480						

CRI (R_a)	Lumen Flux		Sorting[1] @ T_J = 85 °C (lm)		CCT			
Min.	Rank		Min.	Max.	2700K	3000K	3500K	4000K
90	F	3	2710	2900				
	E	3	2540	2710				
	D	3	2370	2540				
	C	3	2220	2370				
	B	3	2070	2220				
	A	3	1930	2070				
	L	2	1810	1930				
	K	2	1690	1810				
	H	2	1580	1690				
	G	2	1480	1580				
	F	2	1380	1480				

Notes:

1) The COB is tested in pulsed operating condition at rated test current (10 ms pulse width) and rated temperature (T_J = T_C = 85 °C).
2) Samsung maintains measurement tolerance of: Luminous flux = ±7 %, CRI = ±1

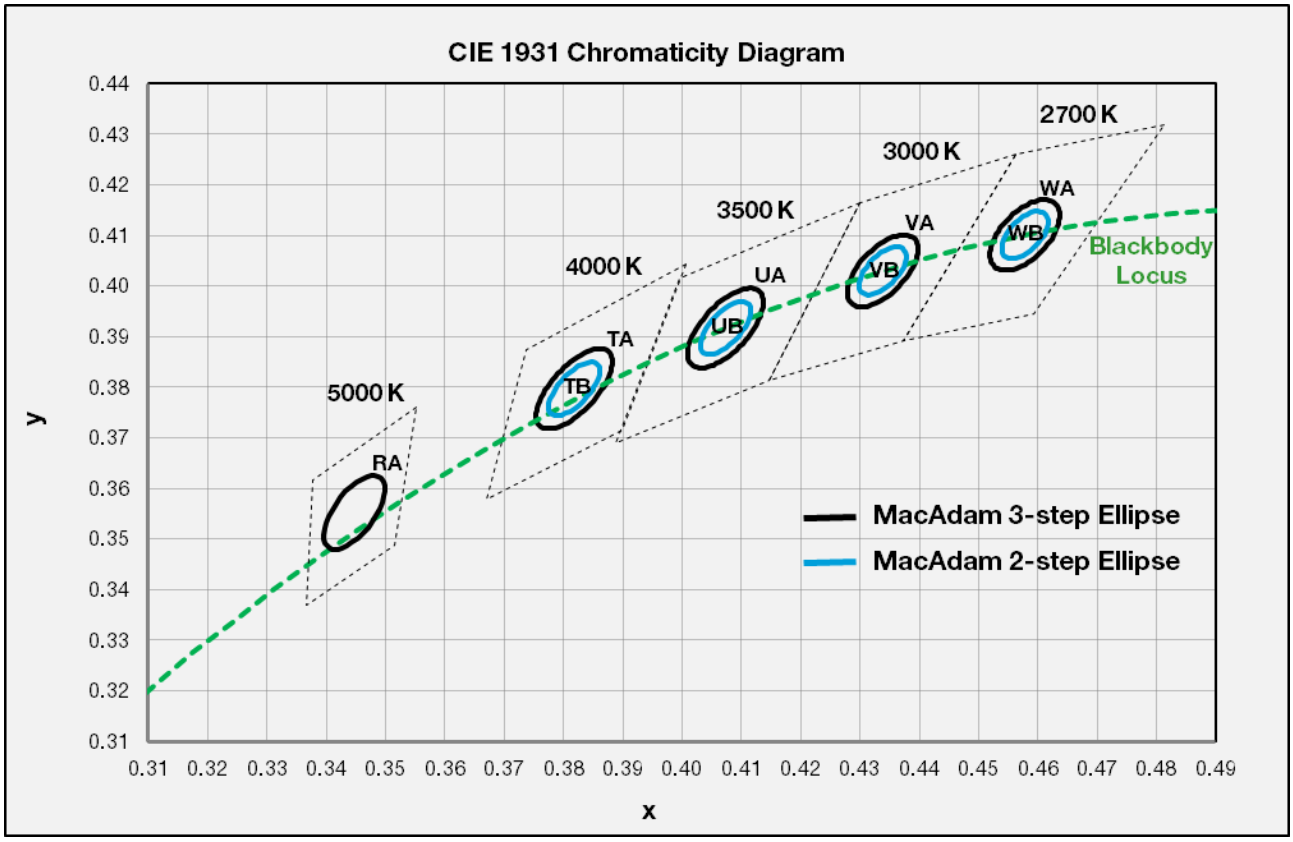
b) Binning Structure (I_F = 540 mA, T_J = 85 ºC)

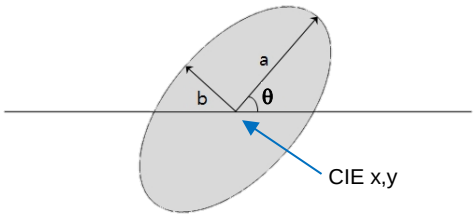
CRI (R_a) Min.	Nominal CCT (K)	Product Code	V_F Rank	Color Rank	Color Bin	Flux Rank	Flux (lm) Typ.	Flux Bin	Flux Range (Φv, lm) Min.	Flux Range (Φv, lm) Max.
80	2700	SPHWH2HDNC05YHW2C1	YH	W2	WB	C1	2140	C 3	2220	2370
								B 3	2070	2220
								A 3	1930	2070
		SPHWH2HDNC05YHW3C1	YH	W3	WA, WB	C1	2140	C 3	2220	2370
								B 3	2070	2220
								A 3	1930	2070
	3000	SPHWH2HDNC05YHV2C1	YH	V2	VB	C1	2230	D 3	2370	2540
								C 3	2220	2370
								B 3	2070	2220
		SPHWH2HDNC05YHV3C1	YH	V3	VA, VB	C1	2230	D 3	2370	2540
								C 3	2220	2370
								B 3	2070	2220
	3500	SPHWH2HDNC05YHU2C1	YH	U2	UB	C1	2320	E 3	2540	2710
								D 3	2370	2540
								C 3	2220	2370
		SPHWH2HDNC05YHU3C1	YH	U3	UA, UB	C1	2320	E 3	2540	2710
								D 3	2370	2540
								C 3	2220	2370
	4000	SPHWH2HDNC05YHT2C1	YH	T2	TB	C1	2380	E 3	2540	2710
								D 3	2370	2540
								C 3	2220	2370
		SPHWH2HDNC05YHT3C1	YH	T3	TA, TB	C1	2380	E 3	2540	2710
								D 3	2370	2540
								C 3	2220	2370
	5000	SPHWH2HDNC05YHR3C1	YH	R3	RA	C1	2520	F 3	2710	2900
								E 3	2540	2710
								D 3	2370	2540
		SPHWH2HDNC05YHRTC1	YH	RT	RW, RX, RY, RZ	C1	2520	F 3	2710	2900
								E 3	2540	2710
								D 3	2370	2540
	5700	SPHWH2HDNC05YHQTC1	YH	QT	QW, QX, QY, QZ	C1	2520	F 3	2710	2900
								E 3	2540	2710
								D 3	2370	2540

b) Binning Structure (I_F = 540 mA, T_J = 85 ºC)

CRI (R_a) Min.	Nominal CCT (K)	Product Code	V_F Rank	Color Rank	Color Bin	Flux Rank	Flux (lm) Typ.	Flux Bin		Flux Range (Φv, lm) Min.	Max.
90	2700	SPHWH2HDNC07YHW2C1	YH	W2	WB	C1	1600	K	2	1690	1810
								H	2	1580	1690
								G	2	1480	1580
		SPHWH2HDNC07YHW3C1	YH	W3	WA, WB	C1	1600	K	2	1690	1810
								H	2	1580	1690
								G	2	1480	1580
	3000	SPHWH2HDNC07YHV2C1	YH	V2	VB	C1	1730	L	2	1810	1930
								K	2	1690	1810
								H	2	1580	1690
		SPHWH2HDNC07YHV3C1	YH	V3	VA, VB	C1	1730	L	2	1810	1930
								K	2	1690	1810
								H	2	1580	1690
	3500	SPHWH2HDNC07YHU2C1	YH	U2	UB	C1	1850	A	3	1930	2070
								L	2	1810	1930
								K	2	1690	1810
		SPHWH2HDNC07YHU3C1	YH	U3	UA, UB	C1	1850	A	3	1930	2070
								L	2	1810	1930
								K	2	1690	1810
	4000	SPHWH2HDNC07YHT2C1	YH	T2	TB	C1	1950	B	3	2070	2220
								A	3	1930	2070
								L	2	1810	1930
		SPHWH2HDNC07YHT3C1	YH	T3	TA, TB	C1	1950	B	3	2070	2220
								A	3	1930	2070
								L	2	1810	1930

c) Chromaticity Region & Coordinates (T_J = 85 ºC)





MacAdam Ellipse (WA, WB)					
Step	CIE x	CIE y	θ	a	b
2-step	0.4578	0.4101	53.70	0.0054	0.0028
3-step	0.4578	0.4101	53.70	0.0081	0.0042

MacAdam Ellipse (VA, VB)					
Step	CIE x	CIE y	θ	a	b
2-step	0.4338	0.4030	53.22	0.0056	0.0027
3-step	0.4338	0.4030	53.22	0.0083	0.0041

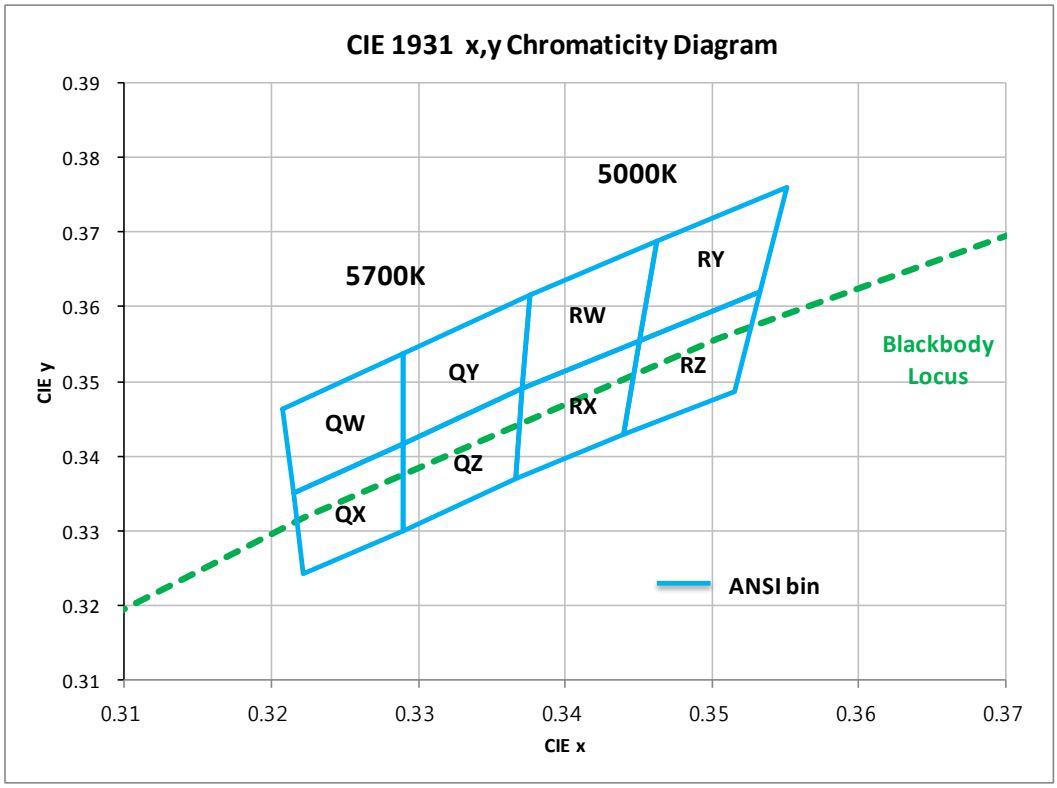
MacAdam Ellipse (UA, UB)					
Step	CIE x	CIE y	θ	a	b
2-step	0.4073	0.3917	54.00	0.0062	0.0028
3-step	0.4073	0.3917	54.00	0.0093	0.0041

MacAdam Ellipse (TA, TB)					
Step	CIE x	CIE y	θ	a	b
2-step	0.3818	0.3797	53.72	0.0063	0.0027
3-step	0.3818	0.3797	53.72	0.0094	0.0040

MacAdam Ellipse (RA)					
Step	CIE x	CIE y	θ	a	b
3-step	0.3447	0.3553	59.62	0.0082	0.0035

Note : Samsung maintains measurement tolerance of: Cx, Cy = ±0.005

c) Chromaticity Region & Coordinates (T_J = 85 °C)



Region	CIE x	CIE y	Region	CIE x	CIE y
R rank (5000 K)					
RW	0.3376	0.3616	RY	0.3463	0.3687
	0.3463	0.3687		0.3551	0.3760
	0.3451	0.3554		0.3533	0.3620
	0.3371	0.3490		0.3451	0.3554
RX	0.3371	0.3490	RZ	0.3451	0.3554
	0.3451	0.3554		0.3533	0.3620
	0.3440	0.3428		0.3515	0.3487
	0.3366	0.3369		0.3440	0.3428

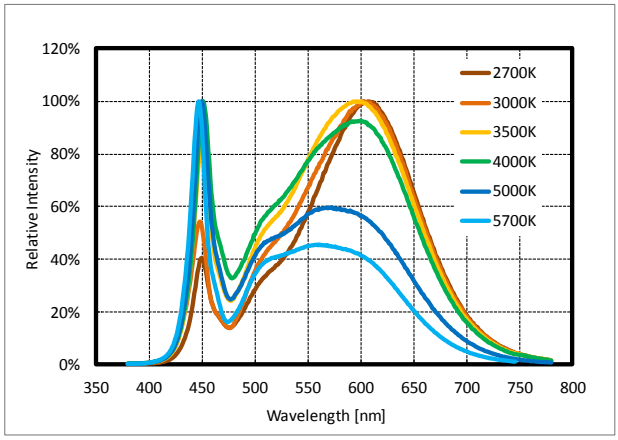
Region	CIE x	CIE y	Region	CIE x	CIE y
Q rank (5700 K)					
QW	0.3207	0.3462	QY	0.3290	0.3538
	0.3290	0.3538		0.3376	0.3616
	0.3290	0.3417		0.3371	0.3490
	0.3215	0.3350		0.3290	0.3417
QX	0.3215	0.3350	QZ	0.3290	0.3417
	0.3290	0.3417		0.3371	0.3490
	0.3290	0.3300		0.3366	0.3369
	0.3222	0.3243		0.3290	0.3300

Note : Samsung maintains measurement tolerance of: Cx, Cy = ±0.005

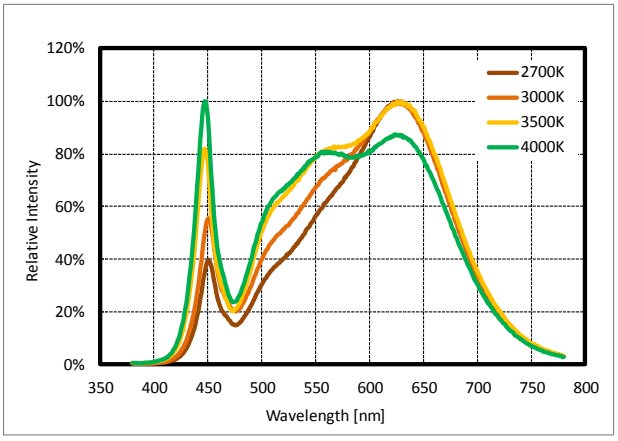
3. Typical Characteristics Graphs

a) Spectrum Distribution (I_F = 540 mA, T_J = 85 ºC)

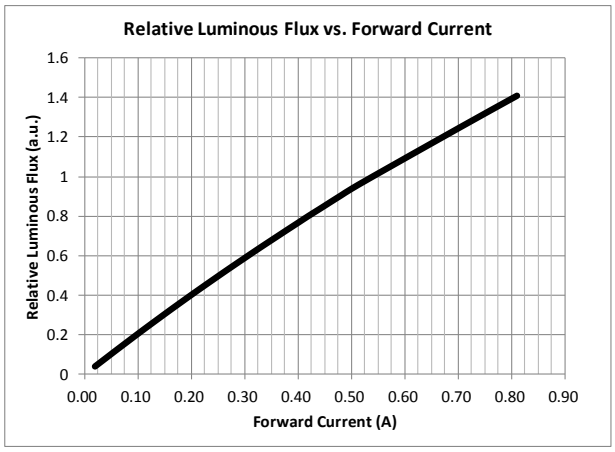
CRI Ra 80+

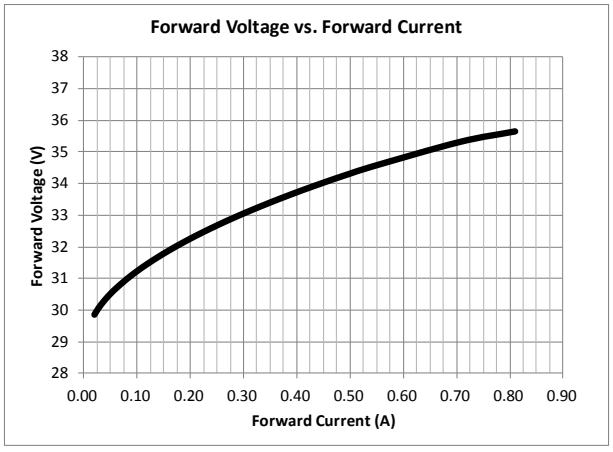


CRI Ra 90+

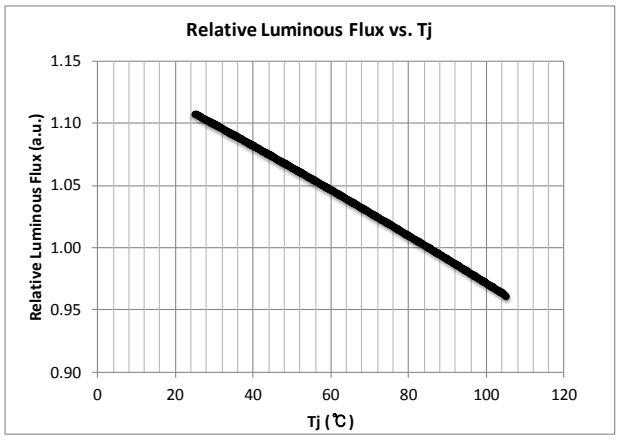


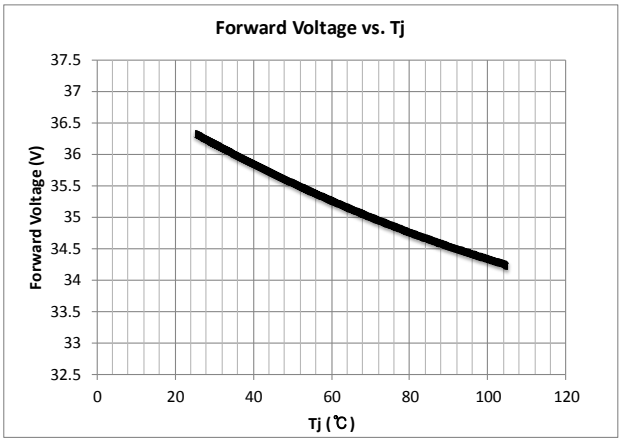
b) Forward Current Characteristics (T_J = 85 ºC)



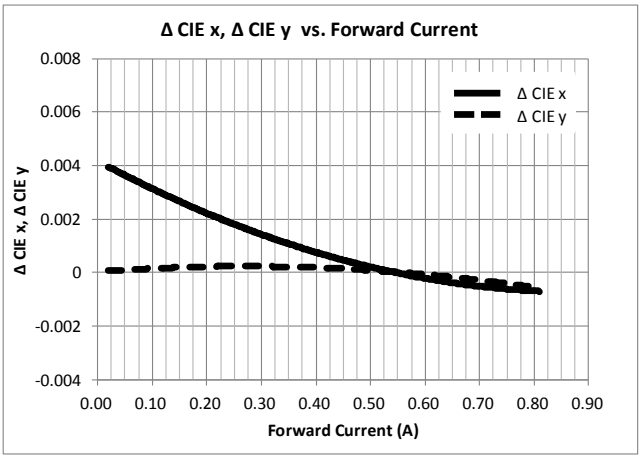


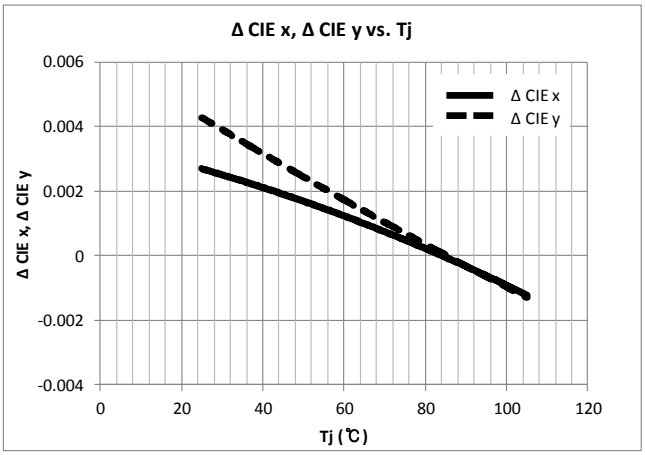
c) Temperature Characteristics (I_F = 540 mA)





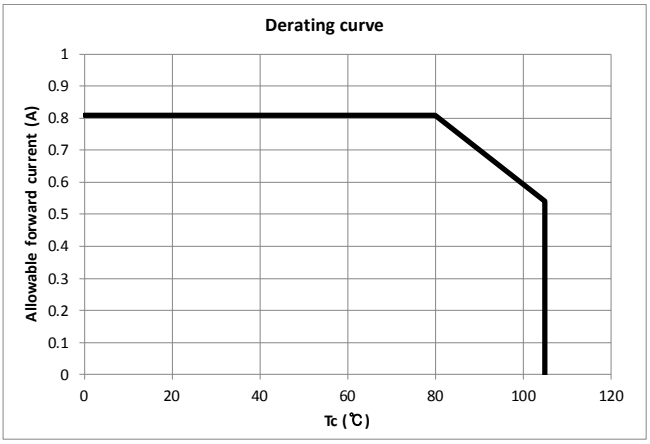
d) Color Shift Characteristics T_J = 85℃ I_F = 540 mA



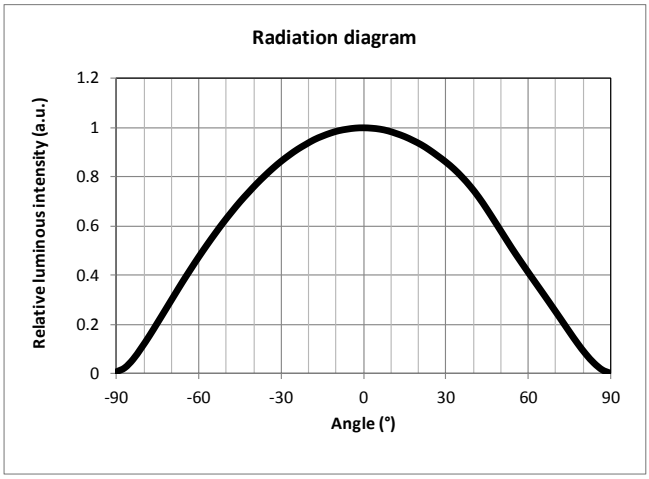


e) Derating Characteristics

Case temperature vs. Allowable Forward Current

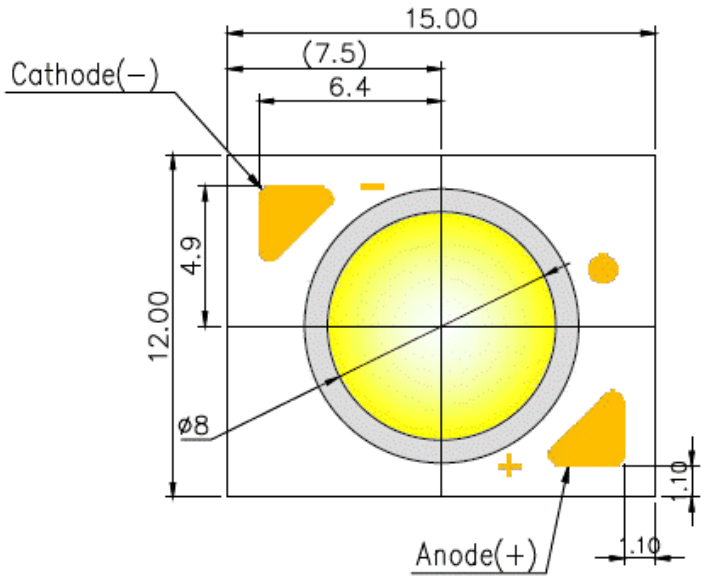


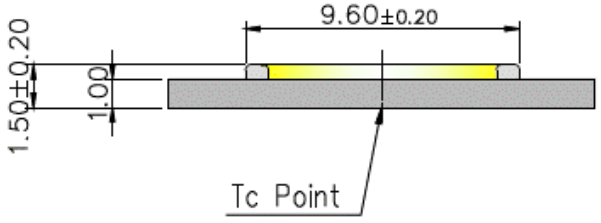
f) Beam Angle Characteristics (I_F = 540 mA, T_a = 25 ºC)



4. Outline Drawing & Dimension

1. Unit: mm
2. Tolerance: ± 0.20 mm





1. Unit: mm
2. Tolerance: ± 0.2 mm

Note : Tc point : The Center of the back side of substrate.

Item	Dimension	Tolerance	Unit
Length	15.00	±0.20	mm
Width	12.00	±0.20	mm
Height	1.50	±0.20	mm
Light Emitting Surface (LES) Diameter	8	±0.15	mm

5. Reliability Test Items & Conditions

a) Test Items

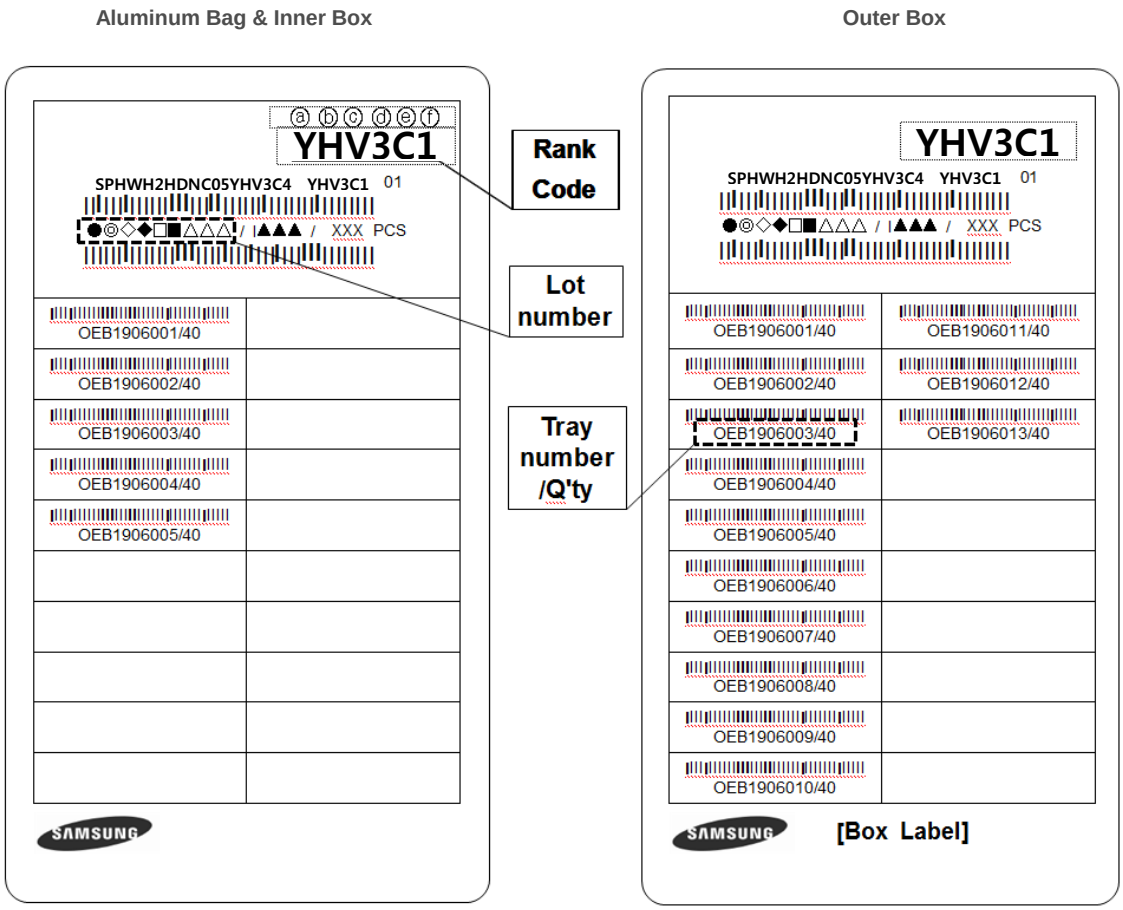
Test Item	Test Condition	Test Hour / Cycle
High Temperature Humidity Life Test	60 ºC, 90 % RH,, DC Derating, I_F	1000 h
High Temperature Life Test	85 ºC, DC Derating, I_F	1000 h
Low Temperature Life Test	-40 ºC, DC 810 mA	1000 h
Pulsed Operating Life Test	55 ℃, Pulse width 100 μs, duty cycle 3 %	1000 h
High Temperature Storage	120 ºC	1000 h
Low Temperature Storage	-40 ºC	1000 h
Temperature Humidity Storage	60 ºC, 90% RH	1000h
Thermal Cycle	-45 ºC / 15 min ↔ 125 ºC / 15 min temperature change in 5 min	800 cycles
Temperature Cycle On/Off Test	-40 ºC / 85 ºC each 20 min, 30 min transfer power on/off each 5 min, DC Derating, I_F = max	100 cycles
ESD (HBM)	R_1: 10 MΩ R_2: 1.5 kΩ C: 100 pF V: ±2 kV	3 times
ESD (MM)	R_1: 10 MΩ R_2: 0 kΩ C: 200 pF V: ±0.2 kV	3 times
Vibration Test	20 ~ 80 Hz (displacement: 0.06 inch, max. 20 g) 80 ~ 2 kHz (max. 20 g) min. frequency ↔ max. frequency 4 min transfer	4 times
Mechanical Shock Test	1500 g, 0.5 ms each of the 6 surfaces (3 axis x 2 sides)	5 times
Sulfur Resistance	25 °C, 75%, H2S 15 ppm	504h

b) Criteria for Judging the Damage

Item	Symbol	Test Condition (T_c = 25 ºC)	Limit	
			Min.	Max.
Forward Voltage	V_F	I_F = 540 m A	L.S.L. * 0.9	U.S.L. * 1.1
Luminous Flux	Φ_v	I_F = 540 m A	L.S.L * 0.7	U.S.L * 1.3

6. Label Structure

a) Label Structure



Note: Denoted rank code and product code above is only an example (see description on page 6)

Rank Code:

ⓐⓑ: Forward Voltage rank (refer to page 3)

ⓒⓓ: Chromaticity bin (refer to page 5-6)

ⓔⓕ: Luminous Flux bin (refer to page 4)

b) Lot Number

The lot number is composed of the following characters:

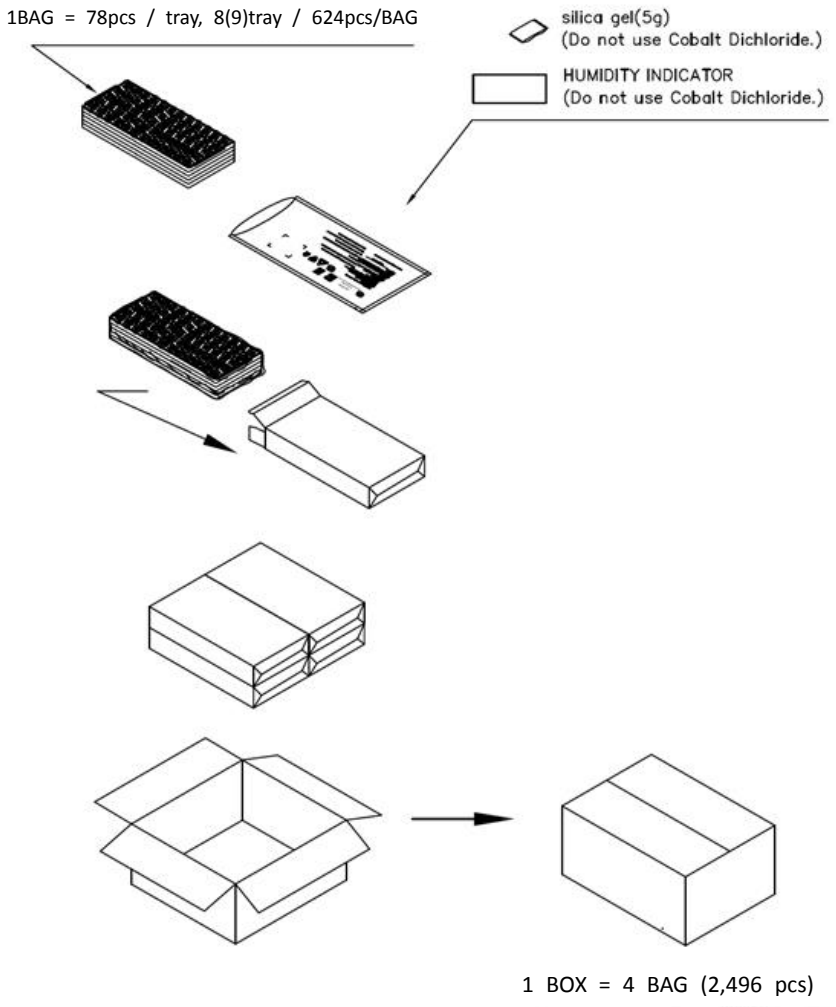
●◎◇◆□■△△△ / 1▲▲▲ / xxx PCS

●	:	Production site (S: Giheung, Korea, G: Tianjin, China)
◎	:	L (LED)
◇	:	Product state (A: Normal, B: Bulk, C: First Production, R: Reproduction, S: Sample)
◆	:	Year (Y: 2014, Z: 2015 , A: 2016, …)
□	:	Month (1~9, A, B, C)
■	:	Day (1~9, A, B~V)
△△△	:	Product serial number (001 ~ 009)
▲▲▲	:	Tray number (001 ~ 999)

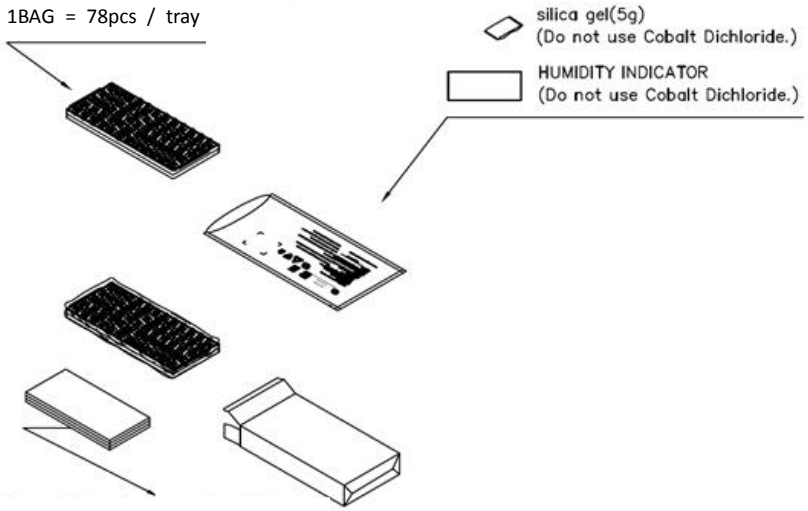
7. Packing Structure

Packing material	Max. quantity in pcs of COB	Dimension (mm)			
		Length	Width	Height	Tolerance
Tray	78	322.6	135.9	11	0.25
Aluminum Bag	624 (8 trays)	450	230	-	10
PE Foam Pad	-	280	130	10	2
Inner Box	624 (1 aluminum bag)	338	148	55	2
Outer Box	2,496 (4 inner boxes)	351	308	120	5
Pallet	139,776 (56 outer boxes)	1000	1000	970	10

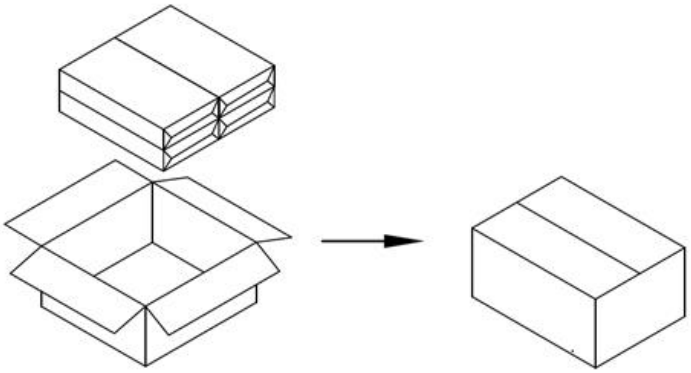
a) Packing Structure for 8 trays inside Aluminum Bag



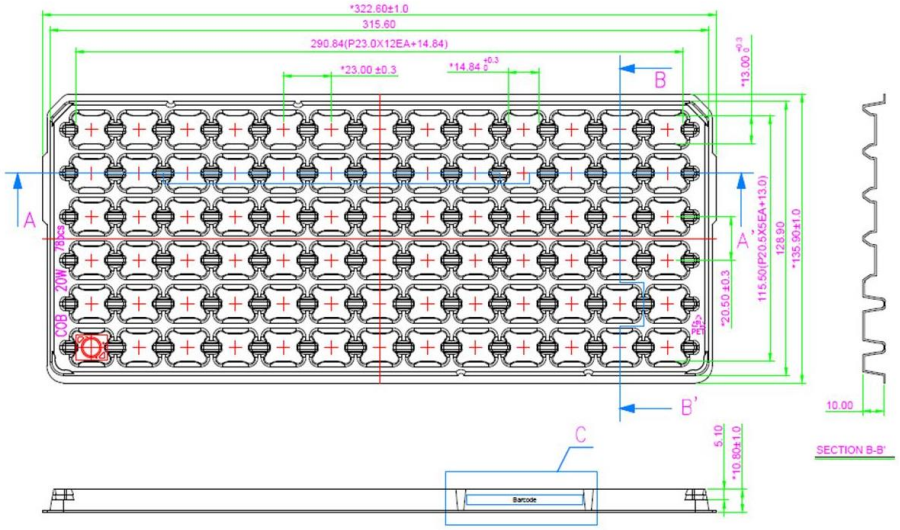
b) Packing Structure for <8 trays inside Aluminum Bag



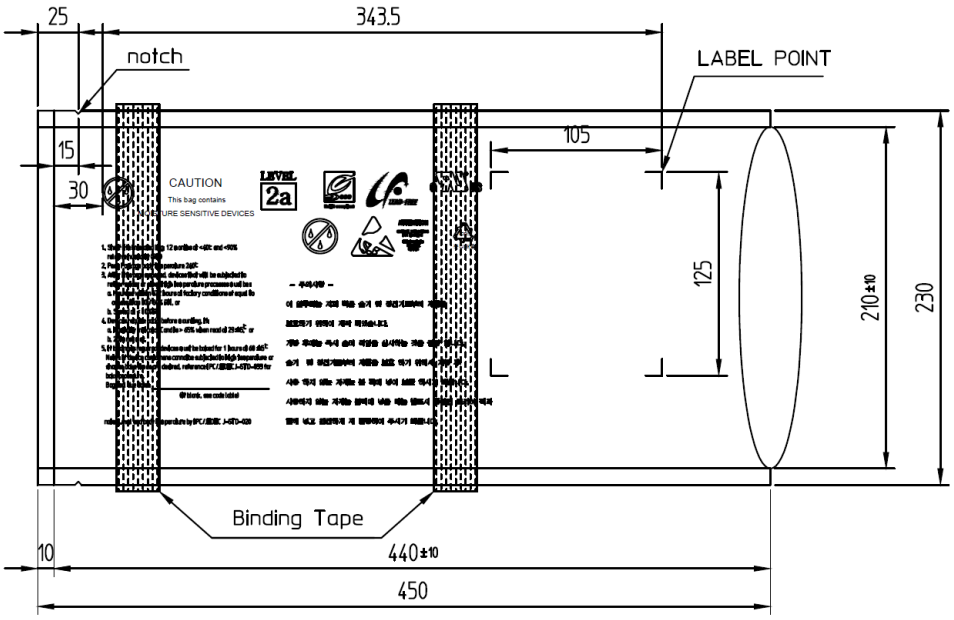
PE foam pad is used as buffer for < 8 trays inside an aluminum bag



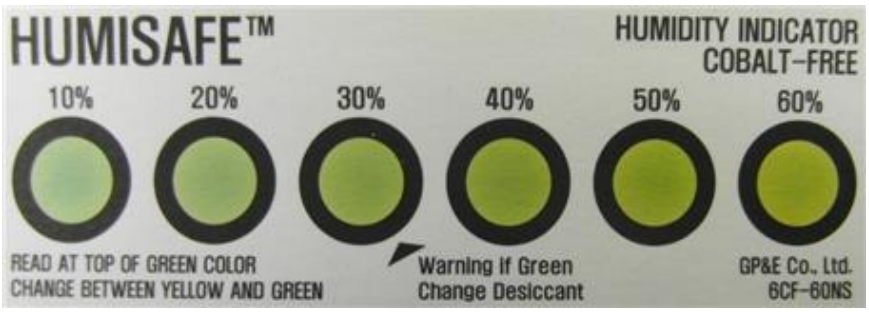
c) Tray



d) Aluminum Vinyl Packing Bag



e) Silica Gel & Humidity Indicator Card inside Aluminum Vinyl Packing Bag

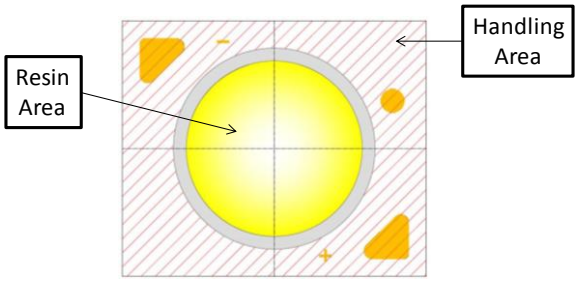


8. Precautions in Handling & Use

1) This device should not be used in any type of fluid such as water, oil, organic solvent, etc. When cleaning is required, IPA is recommended as the cleaning agent. Some solvent-based cleaning agent may damage the silicone resins used in the device.
2) LEDs must be stored in a clean environment. If the LEDs are to be stored for three months or more after being shipped from Samsung, they should be packed with a nitrogen-filled container (shelf life of sealed bags is 12 months at temperature 0~40 ºC, 0~90 % RH).
3) After storage bag is opened, device subjected to soldering or other high temperature processes must be:
   a. Mounted within 672 hours (28 days) at an assembly line with a condition of no more than 30 ºC / 60 % RH, or
   b. Stored at <10 % RH
4) Repack unused products with anti-moisture packing, fold to close any opening and then store in a dry place.
5) Devices require baking before mounting, if humidity card reading is >60 % at 23 ± 5 ºC.
6) Devices must be baked for 1 hour at 60 ± 5 ºC, if baking is required.
7) The LEDs are sensitive to the static electricity and surge current. It is recommended to use a wrist band or anti-electrostatic glove when handling the LEDs. If voltage exceeding the absolute maximum rating is applied to LEDs, it may cause damage or even destruction to LED devices. Damaged LEDs may show some unusual characteristics such as increase in leakage current, lowered turn-on voltage, or abnormal lighting of LEDs at low current.
8) The thermal management is one of the most critical factors for the LED lighting system. Especially the LED junction temperature should not exceed the absolute maximum rating while operation of LED lighting system.

   For more information, please refer to Application Note ‘Mechanical & Thermal Guide for COB’.
9) In case of driving the LC020C around the minimum current level (If_min), chips might exhibit different brightness due to the variation in I-V characteristics of each one. This is normal and does not adversely affect the performance of product.
10) VOCs (Volatile Organic Compounds) can be generated from adhesives, flux, hardener or organic additives used in luminaires (fixtures). Transparent LED silicone encapsulant is permeable to those chemicals and they may lead to a discoloration of encapsulant when they exposed to heat or light. This phenomenon can cause a significant loss of light emitted (output) from the luminaires. In order to prevent these problems, we recommend users to know the physical properties of materials used in luminaires and they must be carefully selected.
11) The resin area is very sensitive, please do not handle, press, touch, rub, clean, or pick by with tweezers on it. Instead, please pick at the handling area as indicated below.

    For more information, please refer to Application Note ‘LED Handling Guide’.



Legal and additional information.

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Samsung Electronics Co., Ltd. inspires the world and shapes the future with transformative ideas and technologies, redefining the worlds of TVs, smartphones, wearable devices, tablets, cameras, digital appliances, printers, medical equipment, network systems and semiconductors. We are also leading in the Internet of Things space through, among others, our Digital Health and Smart Home initiatives. We employ 307,000 people across 84 countries. To discover more, please visit our official website at www.samsung.com and our official blog at global.samsungtomorrow.com.

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